

Bias Resistor Transistor

NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

LDTC115ELT1G

● **Applications**

Inverter, Interface, Driver

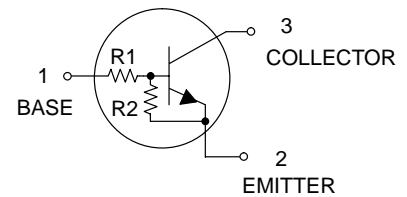
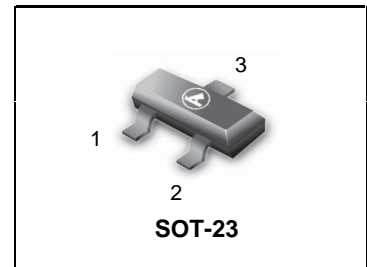
● **Features**

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making the device design easy.

- We declare that the material of product compliance with RoHS requirements.

● **Absolute maximum ratings** (Ta=25°C)

Parameter	Symbol	Limits	Unit
Supply voltage	V _{cc}	50	V
Input voltage	V _i	-10 to +40	V
Output current	I _o	20	mA
	I _{C(Max.)}	100	mA
Collector Power dissipation	P _c	200	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1 (K)	R2 (K)	Shipping
LDTC115ELT1G	N6	100	100	3000/Tape & Reel
LDTC115ELT3G	N6	100	100	10000/Tape & Reel

● **Electrical characteristics** (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{i(off)}	-	-	0.5	V	V _{cc} =5V, I _o =100μA
	V _{i(on)}	3	-	-		V _o =0.3V, I _o =1mA
Output voltage	V _{o(on)}	-	0.1	0.3	V	I _o =5mA, I _i =0.25mA
Input current	I _i	-	-	0.15	mA	V _i =5V
Output current	I _{o(off)}	-	-	0.5	μA	V _{cc} =50V, V _i =0V
DC current gain	G _i	82	-	-	-	I _o =5mA, V _o =5V
Input resistance	R _i	70	100	130	kΩ	-
Resistance ratio	R ₂ /R ₁	0.8	1	1.2	-	-
Transition frequency	f _t *	-	250	-	MHz	V _{ce} =10V, I _E =-5mA, f=100MHz

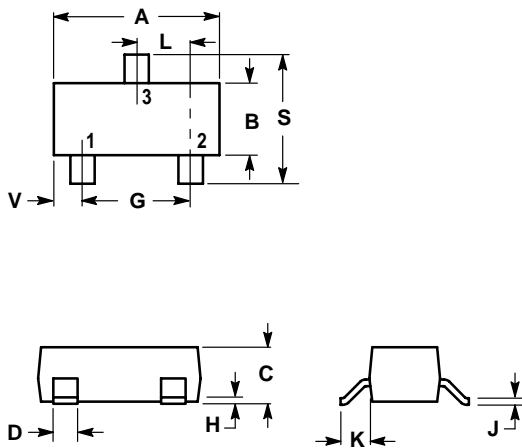
* Characteristics of built-in transistor

LDT C115ELT1G

SOT-23

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

